

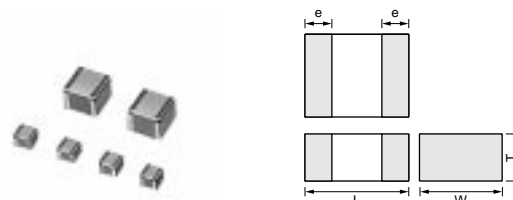
CHIP MONOLITHIC CERAMIC CAPACITOR

muRata

High-Q & High-power GRH/RPN100 Series

■ Features(GRH100 Series)

1. The dielectric is composed of low dielectric loss ceramics. This series is perfectly suited to high-frequency applications (VHS-microwave band).
2. The series is ultraminiature, yet has a high-power capacity. This is the best capacitor available for transmitter and amplifier circuits such as those in broadcasting equipment and mobile base stations.
3. GRH110 type is designed for both flow and reflow soldering and GRH111 type is designed for reflow soldering.
4. GRH type capacitors exhibit better solderability and lower solder leaching because of its nickel barriered terminations.



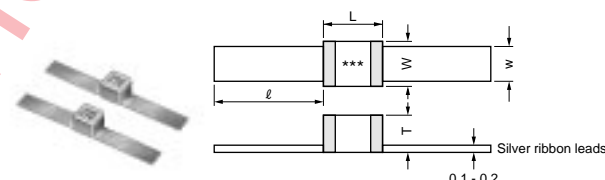
Part Number	Dimensions (mm)			
	L	W	T	e
GRH110	1.4 ^{+0.6} _{-0.4}	1.4 ^{+0.6} _{-0.4}	0.8 to 1.65	0.25 ^{+0.25} _{-0.15}
GRH111	2.8 ^{+0.6} _{-0.4}	2.8 ^{+0.6} _{-0.4}	2.0 to 2.8	0.4 ^{+0.4} _{-0.3}

■ Application

High-frequency and high-power circuits.

■ Features(RPN100 Series)

1. The dielectric is composed of low dielectric loss ceramics. This series is perfectly suited to high-frequency applications (VHS-microwave band).
2. The series is ultraminiature, yet has a high-power capacity. This is the best capacitor available for transmitter and amplifier circuits such as those in broadcasting equipment and mobile base stations.
3. RPN type capacitors withstand high temperatures because ribbon leads are attached with silver paste.
4. RPN type capacitors are easily soldered and especially well suited in applications where only a soldering iron can be used.



Part Number	Dimensions (mm)				
	L	W	T max.	l	w
RPN110	1.6 ±0.4	1.4 ±0.4	1.6	5.0 min.	1.3 ±0.4
RPN111	3.2 ±0.4	2.8 ±0.4	3.0	9.0 ±2.0	2.35 ±0.15


■ Application

High-frequency and high-power circuits.


Part Number	GRH110	GRH111					RPN110	RPN111				
L x W(mm)	1.40x1.40	2.80x2.80					1.60x1.40	3.20x2.80				
TC Code	C0G	C0G					C0G	C0G				
Rated Volt.(Vdc)	50	50	100	200	300	500	50	50	100	200	300	500
Capacitance and T(mm)												
0.5pF	1.20					2.40	1.60					3.00
0.6pF	1.20					2.40	1.60					3.00
0.7pF	1.20					2.40	1.60					3.00
0.8pF	1.20					2.40	1.60					3.00
0.9pF	1.20					2.40	1.60					3.00
1.0pF	1.20					2.40	1.60					3.00
1.1pF	1.20					2.40	1.60					3.00
1.2pF	1.20					2.40	1.60					3.00
1.3pF	1.20					2.40	1.60					3.00
1.4pF	1.20					2.40	1.60					3.00
1.5pF	1.20					2.40	1.60					3.00


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Part Number	GRH110	GRH111					RPN110	RPN111				
L x W(mm)	1.40x1.40	2.80x2.80					1.60x1.40	3.20x2.80				
TC Code	C0G	C0G					C0G	C0G				
Rated Volt.(Vdc)	50	50	100	200	300	500	50	50	100	200	300	500
Capacitance and T(mm)												
1.6pF	1.20					2.40	1.60					3.00
1.7pF	1.20					2.40	1.60					3.00
1.8pF	1.20					2.40	1.60					3.00
1.9pF	1.20					2.40	1.60					3.00
2.0pF	1.20					2.40	1.60					3.00
2.1pF	1.20					2.40	1.60					3.00
2.2pF	1.20					2.40	1.60					3.00
2.4pF	1.20					2.40	1.60					3.00
2.7pF	1.20					2.40	1.60					3.00
3.0pF	1.20					2.40	1.60					3.00
3.3pF	1.20					2.40	1.60					3.00
3.6pF	1.20					2.40	1.60					3.00
3.9pF	1.20					2.40	1.60					3.00
4.3pF	1.20					2.40	1.60					3.00
4.7pF	1.20					2.40	1.60					3.00
5.1pF	1.20					2.40	1.60					3.00
5.6pF	1.20					2.40	1.60					3.00
6.2pF	1.20					2.40	1.60					3.00
6.8pF	1.20					2.40	1.60					3.00
7.5pF	1.20					2.40	1.60					3.00
8.2pF	1.20					2.40	1.60					3.00
9.1pF	1.20					2.40	1.60					3.00
10.0pF	1.20					2.40	1.60					3.00
11pF	1.20					2.40	1.60					3.00
12pF	1.20					2.40	1.60					3.00
13pF	1.20					2.40	1.60					3.00
15pF	1.20					2.40	1.60					3.00
16pF	1.20					2.40	1.60					3.00
18pF	1.20					2.40	1.60					3.00
20pF	1.20					2.40	1.60					3.00
22pF	1.20					2.40	1.60					3.00
24pF	1.20					2.40	1.60					3.00
27pF	1.20					2.40	1.60					3.00
30pF	1.20					2.40	1.60					3.00
33pF	1.20					2.40	1.60					3.00
36pF	1.20					2.40	1.60					3.00
39pF	1.20					2.40	1.60					3.00
43pF	1.20					2.40	1.60					3.00
47pF	1.20					2.40	1.60					3.00
51pF	1.20					2.40	1.60					3.00
56pF	1.20					2.40	1.60					3.00
62pF	1.20					2.40	1.60					3.00
68pF	1.20					2.40	1.60					3.00
75pF	1.20					2.40	1.60					3.00
82pF	1.20					2.40	1.60					3.00
91pF	1.20					2.40	1.60					3.00
100pF	1.20					2.40	1.60					3.00
110pF					2.40							3.00
120pF					2.40							3.00
130pF					2.40							3.00
150pF					2.40							3.00
160pF					2.40							3.00
180pF					2.40							3.00
200pF					2.40							3.00


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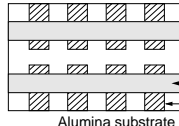
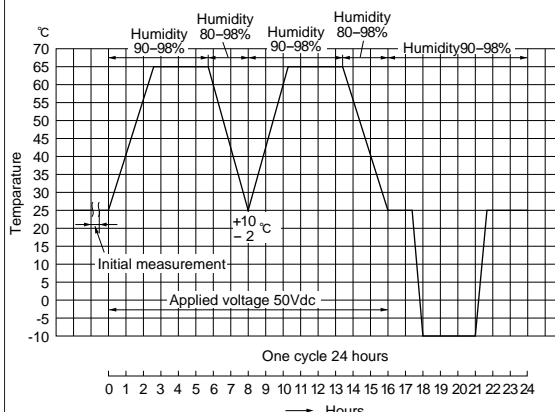
Part Number	GRH110	GRH111					RPN110	RPN111				
L x W(mm)	1.40x1.40	2.80x2.80					1.60x1.40	3.20x2.80				
TC Code	C0G	C0G					C0G	C0G				
Rated Volt.(Vdc)	50	50	100	200	300	500	50	50	100	200	300	500
Capacitance and T(mm)												
220pF				2.40						3.00		
240pF				2.40						3.00		
270pF				2.40						3.00		
300pF				2.40						3.00		
330pF				2.40						3.00		
360pF				2.40						3.00		
390pF				2.40						3.00		
430pF				2.40						3.00		
470pF				2.40						3.00		
510pF			2.40						3.00			
560pF			2.40						3.00			
620pF			2.40						3.00			
680pF			2.40						3.00			
750pF		2.40						3.00				
820pF		2.40						3.00				
910pF		2.40						3.00				
1000pF		2.40						3.00				

Specifications and Test Methods

No.	Item		Specification	Test Method												
1	Operating Temperature Range		−55℃ to +125℃													
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, shall be maintained within the rated voltage range.												
3	Appearance		No defects or abnormalities.	Visual inspection.												
4	Dimensions		Within the specified dimension.	Using calipers.												
5	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.												
6	Insulation Resistance (I.R.)	25℃	$C \leq 470\text{pF}$: 1,000,000MΩ min. $470\text{pF} < C \leq 1,000\text{pF}$: 100,000MΩ min.	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 125℃ standard humidity and within 2 minutes of charging.												
		125℃	$C \leq 470\text{pF}$: 100,000MΩ min. $470\text{pF} < C \leq 1,000\text{pF}$: 10,000MΩ min.													
7	Capacitance		Within the specified tolerance.	The capacitance/Q shall be measured at 25℃ at the frequency and voltage shown in the table. <table><tr><th>Item</th><th>Char.</th><th>C0G (1,000pF and below)</th></tr><tr><td>Frequency</td><td></td><td>1±0.1MHz</td></tr><tr><td>Voltage</td><td></td><td>0.5 to 5Vr.m.s.</td></tr></table>	Item	Char.	C0G (1,000pF and below)	Frequency		1±0.1MHz	Voltage		0.5 to 5Vr.m.s.			
Item	Char.	C0G (1,000pF and below)														
Frequency		1±0.1MHz														
Voltage		0.5 to 5Vr.m.s.														
8	Q		$C \leq 220\text{pF}$: $Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF}$: $Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF}$: $Q \geq 3,000$ C : Nominal Capacitance (pF)													
9	Capacitance Temperature Characteristics	Capacitance Variation Rate	Within the specified tolerance. (Table A-7)	The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap. value in step 3. The capacitance change shall be measured after 5 min. at each specified temperature stage. <table><tr><th>Step</th><th>Temperature(℃)</th></tr><tr><td>1</td><td>25±2</td></tr><tr><td>2</td><td>−55±3</td></tr><tr><td>3</td><td>25±2</td></tr><tr><td>4</td><td>125±3</td></tr><tr><td>5</td><td>25±2</td></tr></table>	Step	Temperature(℃)	1	25±2	2	−55±3	3	25±2	4	125±3	5	25±2
		Step	Temperature(℃)													
		1	25±2													
		2	−55±3													
3	25±2															
4	125±3															
5	25±2															
10	Terminal Strength	Adhesive Strength of Termination (for chip type)	No removal of the terminations or other defects shall occur.													
		Tensile Strength (for micro-strip type)	Capacitor shall not be broken or damaged.													
		Bending Strength of lead wire terminal (for micro-strip type)	Lead wire shall not be cut or broken.													


Continued on the following page. 

Specifications and Test Methods

No.	Item		Specification	Test Method															
11	Vibration Resistance	Appearance	No defects or abnormalities.	<p>Solder the capacitor to the test jig (alumina substrate) shown in Fig.2 using solder containing 2.5% silver. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so the soldering is uniform and free of defects such as heat shock.The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).</p> <div><p>Solder resist Ag/Pd Alumina substrate</p></div> <p>Fig. 2</p>															
		Capacitance	Within the specified tolerance.																
		Q	<p>Satisfies the initial value.</p> <p>$C \leq 220\text{pF} : Q \geq 10,000$</p> <p>$220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$</p> <p>$470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$</p> <p>C : Nominal Capacitance (pF)</p>																
12	Solderability of Termination		95% of the terminations is to be soldered evenly and continuously.	<p>Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating immerse in solder containing 2.5% silver for 5±0.5 seconds at 230±5°C. The dipping depth for microstrip type capacitors is up to 1 mm from the root of the terminal.</p>															
13	Resistance to Soldering Heat		The measured and observed characteristics shall satisfy the specifications in the following table.	<p>Preheat the capacitor at 80 to 100°C for 2 minutes and then at 150 to 200°C for 5 minutes.</p> <p>Immerse in solder containing 2.5% silver for 3±0.5 seconds at 270±5°C. Set at room temperature for 24±2 hours, then measure. The dipping depth for microstrip type capacitors is up to 2mm from the root of the terminal.</p>															
			<table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>Within ±2.5% or ±0.25pF (Whichever is larger)</td></tr><tr><td>Q</td><td>$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$</td></tr><tr><td>I.R.</td><td>More than 30% of the initial specification value at 25°C.</td></tr><tr><td>Dielectric Strength</td><td>No failure</td></tr></table> <p>C : Nominal Capacitance (pF)</p>		Item	Specification	Appearance	No marked defect	Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Q	$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$	I.R.	More than 30% of the initial specification value at 25°C.	Dielectric Strength	No failure			
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I.R.	More than 30% of the initial specification value at 25°C.																		
Dielectric Strength	No failure																		
14	Temperature Cycle		The measured and observed characteristics shall satisfy the specifications in the following table.	<p>Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11). Perform the five cycles according to the four heat treatments listed in the following table. Then, repeat twice the successive cycles of immersion, each cycle consisting of immersion in a fresh water at 65±5°C for 15 minutes and immersion in a saturated aqueous solution of salt at 0±3°C for 15 minutes.</p> <p>The capacitor is promptly washed with running water, dried with a dry cloth, and allowed to sit at room temperature for 24±2 hours.</p> <table><tr><th>Step</th><th>1</th><th>2</th><th>3</th><th>4</th></tr><tr><td>Temp.(°C)</td><td>-55±3</td><td>RoomTemp.</td><td>125±3</td><td>RoomTemp.</td></tr><tr><td>Time(min.)</td><td>30±3</td><td>2 to 3</td><td>30±3</td><td>2 to 3</td></tr></table>	Step	1	2	3	4	Temp.(°C)	-55±3	RoomTemp.	125±3	RoomTemp.	Time(min.)	30±3	2 to 3	30±3	2 to 3
			Step		1	2	3	4											
Temp.(°C)	-55±3	RoomTemp.	125±3	RoomTemp.															
Time(min.)	30±3	2 to 3	30±3	2 to 3															
			<table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>Within ±1% or ±0.25pF (Whichever is larger)</td></tr><tr><td>Q</td><td>$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$</td></tr><tr><td>I.R.</td><td>More than 30% of the initial specification value at 25°C.</td></tr><tr><td>Dielectric Strength</td><td>No failure</td></tr></table> <p>C : Nominal Capacitance (pF)</p>	Item	Specification	Appearance	No marked defect	Capacitance Change	Within ±1% or ±0.25pF (Whichever is larger)	Q	$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$	I.R.	More than 30% of the initial specification value at 25°C.	Dielectric Strength	No failure				
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I.R.	More than 30% of the initial specification value at 25°C.																		
Dielectric Strength	No failure																		
15	Humidity		The measured and observed characteristics shall satisfy the specifications in the following table.	<p>Apply the 24-hour heat (-10 to +65°C) and humidity (80 to 98%) treatment shown below, 10 consecutive times. Remove, set for 24±2 hours at room temperature, and measure.</p> <div><p>One cycle 24 hours</p><p>Hours</p></div>															
			<table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>Within ±5% or ±0.5pF (Whichever is larger)</td></tr><tr><td>Q</td><td>$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$</td></tr><tr><td>I.R.</td><td>More than 30% of the initial specification value at 25°C.</td></tr></table> <p>C : Nominal Capacitance (pF)</p>		Item	Specification	Appearance	No marked defect	Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	Q	$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$	I.R.	More than 30% of the initial specification value at 25°C.					
Item	Specification																		
Appearance	No marked defect																		
Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)																		
Q	$C \leq 220\text{pF} : Q \geq 10,000$ $220\text{pF} < C \leq 470\text{pF} : Q \geq 5,000$ $470\text{pF} < C \leq 1,000\text{pF} : Q \geq 3,000$																		
I.R.	More than 30% of the initial specification value at 25°C.																		

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Specifications and Test Methods

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No.	Item	Specification	Test Method										
16	High Temperature Load	The measured and observed characteristics shall satisfy the specifications in the following table.	Apply 150% of the rated voltage for 2,000±12 hours at 125±3℃. Remove and set for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.										
		<table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>Within ±2.5% or ±0.25pF (Whichever is larger)</td></tr><tr><td>Q</td><td>C ≤ 220pF : Q ≥ 10,000 220pF < C ≤ 470pF : Q ≥ 5,000 470pF < C ≤ 1,000pF : Q ≥ 3,000</td></tr><tr><td>I.R.</td><td>More than 30% of the initial specification value at 25℃.</td></tr></table>		Item	Specification	Appearance	No marked defect	Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Q	C ≤ 220pF : Q ≥ 10,000 220pF < C ≤ 470pF : Q ≥ 5,000 470pF < C ≤ 1,000pF : Q ≥ 3,000	I.R.	More than 30% of the initial specification value at 25℃.
		Item		Specification									
		Appearance		No marked defect									
		Capacitance Change		Within ±2.5% or ±0.25pF (Whichever is larger)									
		Q		C ≤ 220pF : Q ≥ 10,000 220pF < C ≤ 470pF : Q ≥ 5,000 470pF < C ≤ 1,000pF : Q ≥ 3,000									
I.R.	More than 30% of the initial specification value at 25℃.												
C : Nominal Capacitance (pF)													

Table A

Char.	Temp. Coeff. (ppm/°C) Note 1	Capacitance Change from 25°C Value (%)					
		-55°C		-30°C		-10°C	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0 ± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25 to 125°C.